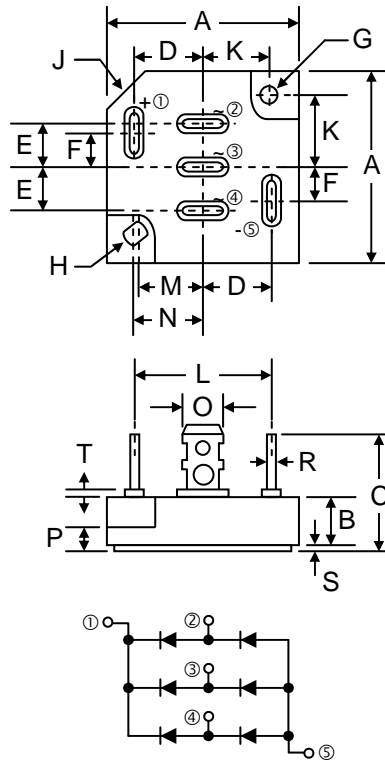


Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- Ideal for Printed Circuit Boards
- Plastic Material has UL Recognition
Flammability Classification Rating 94V-O

Mechanical Data

- Case: Epoxy Case
Mounted in the Bridge Encapsulation
- Terminals: Plated Faston Lugs Solderable
per MIL-STD-202, Method 208
- Polarity: See Diagram Below
- Weight: 37 grams (approx.)
- Mounting Position: Bolt Down on Heatsink
With Silicone Thermal Compound Between
Module and Mounting Surface for Maximum
Heat Transfer Efficiency
- Mounting Torque: 0.8 N.m Max.
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version,
Add “-LF” Suffix to Part Number, See Page 4**



SVT		
Dim	Min	Max
A	—	36.0
B	9.8	10.4
C	—	29.0
D	13.1	14.1
E	8.5	9.5
F	6.5	7.5
G	3.5 Ø Typical	
H	R 1.75 Typical	
J	3.7 x 45°	
K	—	12.8
L	26.2	28.2
M	—	12.5
N	—	13.1
O	6.2	6.5
P	5.5	6.5
R	0.7	0.9
S	1.0	1.8
T	1.4	1.6
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	S30VT60	S30VT80	S30VT160	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	800	1600	V
RMS Reverse Voltage	V _{R(RMS)}	420	560	1120	V
Average Rectified Output Current @T _C = 55°C	I _O	35			A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	350			A
Forward Voltage per diode @I _F = 17.5A	V _{FM}	1.1			V
Peak Reverse Current At Rated DC Blocking Voltage	I _{RM}	10			µA
I ² t Rating for Fusing per diode (1ms < t < 10ms)	I ² t	800			A ² s
Thermal Resistance Junction to Case (Note 1)	R _{θJC}	0.7			°C/W
RMS Isolation Voltage from Case to Leads	V _{ISO}	2000			V
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150			°C

Note: 1. Mounted on 229 x 89 x 117mm Al. finned plate.

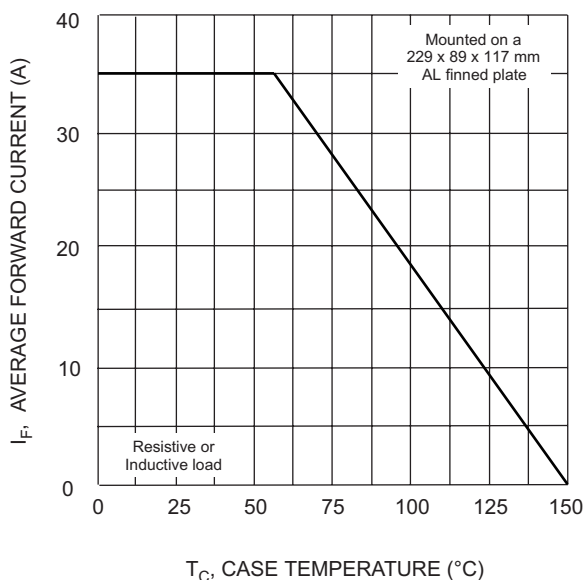


Fig. 1 Forward Current Derating Curve

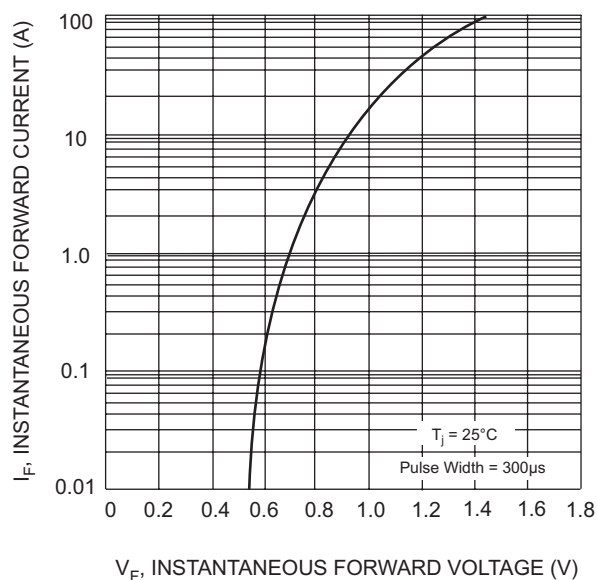


Fig. 2 Typical Forward Characteristics (per element)

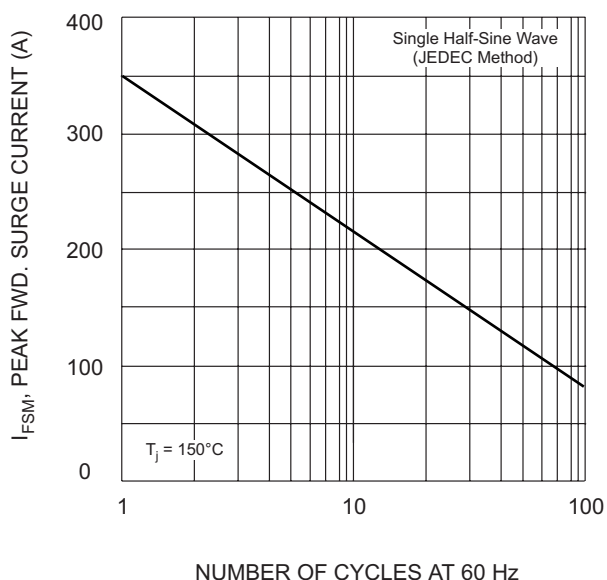


Fig. 3 Max Non-Repetitive Surge Current

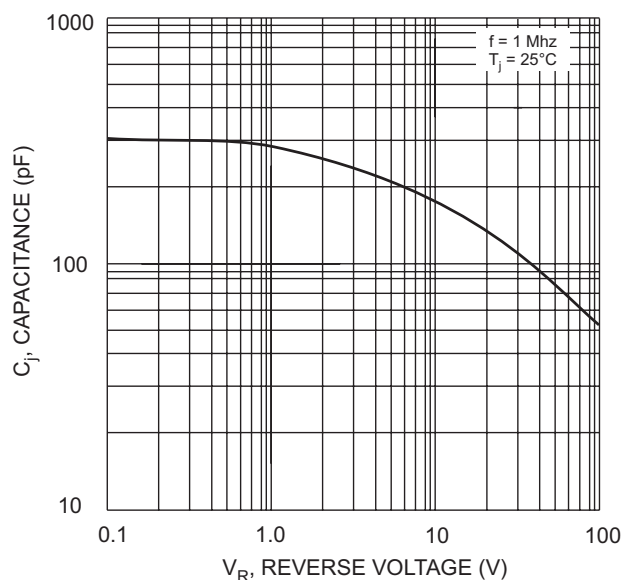


Fig. 4 Typical Junction Capacitance (per element)

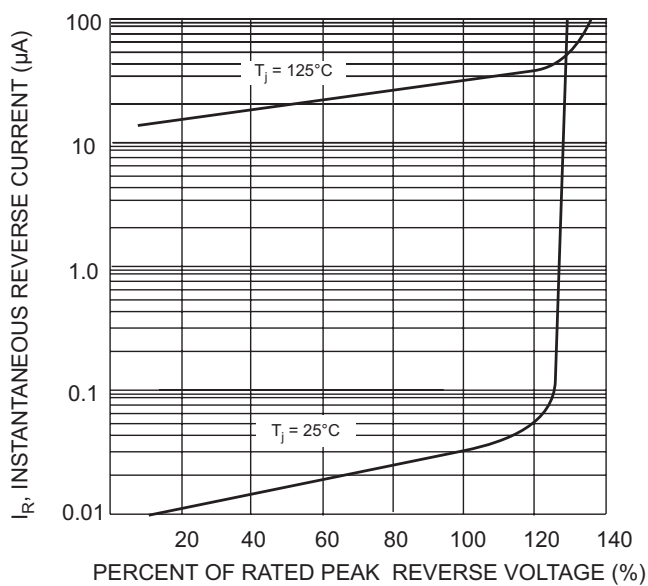
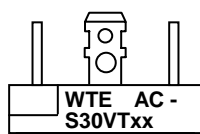


Fig. 5 Typical Reverse Characteristics (per element)

MARKING INFORMATION



WTE = Manufacturer's Logo
S30VTxx = Device Number
xx = 60, 80 or 160
Polarity = As Marked on Body

PACKAGING INFORMATION

BULK

Inner Box Size L x W x H (mm)	Quantity (PCS)	Carton Size L x W x H (mm)	Quantity (PCS)	Approx. Gross Weight (KG)
195 x 195 x 40	25	405 x 205 x 240	250	12.0

Note: 1. Paper box, white or brown color.

ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity
S30VT60	Bridge Module	25 Units/Box
S30VT80	Bridge Module	25 Units/Box
S30VT160	Bridge Module	25 Units/Box

1. Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.
2. **To order Lead Free version (with Lead Free finish), add "-LF" suffix to part number above. For example, S30VT60-LF.**

Won-Top Electronics Co., Ltd (WTE) has checked all information carefully and believes it to be correct and accurate. However, WTE cannot assume any responsibility for inaccuracies. Furthermore, this information does not give the purchaser of semiconductor devices any license under patent rights to manufacturer. WTE reserves the right to change any or all information herein without further notice.

WARNING: DO NOT USE IN LIFE SUPPORT EQUIPMENT. WTE power semiconductor products are not authorized for use as critical components in life support devices or systems without the express written approval.

Won-Top Electronics Co., Ltd.

No. 44 Yu Kang North 3rd Road, Chine Chen Dist., Kaohsiung, Taiwan

Phone: 886-7-822-5408 or 886-7-822-5410

Fax: 886-7-822-5417

Email: sales@wontop.com

Internet: <http://www.wontop.com>

We power your everyday.